

Passive q-switch crystals

Passive Q-switch crystals (saturable absorbers) are used as laser resonator quality modulators in passively Q-switched lasers instead of an electrically controlled modulators. Typically, these saturable absorbers are characterized by a low saturation fluence (saturation energy per unit area) and their use with converging beams can further reduce the saturation energy (saturation fluence times beam area).

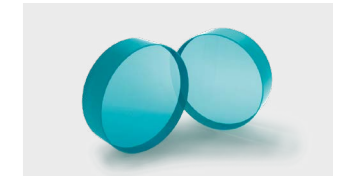
4Lasers develops and supplies different passive Q-switch crystal hosts and ion dopant combinations for research and industrial applications, therefore custom solutions are available upon request.



Cr:YAG crystals

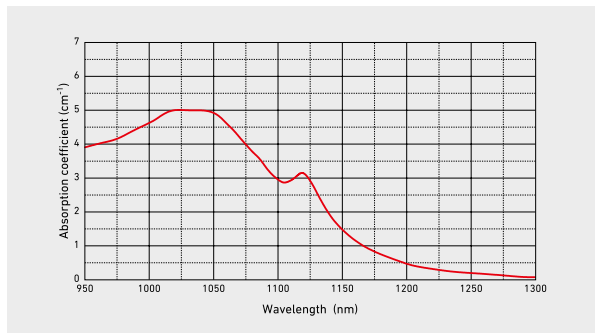


V:YAG crystals



Co:Spinel crystals

Cr:YAG crystals



Cr⁴⁺:YAG crystals are ideal for passive Q-switch operation of Nd:YAG and other Nd³⁺ or Yb³⁺ doped laser crystals in the wavelength range of 900 nm to 1200 nm. Remarkable feature of Cr⁴⁺:YAG is the high

damage threshold of >10 J/cm²@1064 nm, 10 ns. Its absorption band extends from 900 nm to 1200 nm and peaks around 1060 nm with a very large absorption cross-section.

Main features

- Good chemical stability and reliability
- Long lifetime and good thermal conductivity
- Easy to operate
- Custom crystals available upon request

Application examples

- Passively Q-switched lasers for laser rangefinders, LIDAR and LIBS systems
- Laser systems where short pulses are required

Standard specifications

CR:YAG CRYSTALS	
Initial transmission T ₀	5-99 %@1064 nm
Initial transmission T ₀ tolerance	±1% (for values larger than 80 %)
Clear aperture	>90%
Face dimensions tolerance	+0,0/-0,1 mm
Parallelism error	<10 arcsec
Perpendicularity error	<10 arcmin
Protective chamfers	<0,1 mm at 45°
Surface quality	10-5 S-D
Surface flatness	<λ/8@632,8 nm
Wavefront distortion	<λ/4@632,8
Coatings	AR(R<0,15%)@1064 nm on both sides
Laser induced damage threshold	>10 J/cm ² @1064 nm, 10 ns
Mount	Unmounted

Properties

SPECTROSCOPIC AND THERMO-MECHANICAL PROPERTIES						
Material	σ _{gsa} ¹ @1,064 μm	σ _{esa} ² @1,064 μm	τ _{sa} ³	Laser crystal	λ _{laser}	σ _{gsa} /σ _{em} ⁴
Cr ⁴⁺ :Y ₃ Al ₅ O ₁₂	46 × 10 ⁻¹⁹ cm ²	8,2 × 10 ⁻¹⁹ cm ²	3,4 μs	Nd:YAG	0,946 μm	130
				Nd:YAG	1,06 μm	17
				Nd:GSAG	1,06 μm	55
				Nd:YVO ₄	1,06 μm	3,5
				Nd:GdVO ₄	1,06 μm	5
				Nd:LuVO ₄	1,06 μm	3,4
				Nd:LSB	1,06 μm	40
				Nd:YAP	1,08 μm	14
				Yb:NLM	1,01 μm	500
				Yb:YVO ₄	1,02 μm	625
				Yb:GGG	1,025 μm	250
				Yb:YAG	1,03 μm	250
				Yb:LuAG	1,03 μm	185
				Yb:KGW	1,035 μm	185
Crystal structure	Cubic					
Density	4,56 g/cm ³					
Thermal expansion coefficient	6,14 × 10 ⁻⁶ K ⁻¹					
Thermal conductivity	11,2 Wm ⁻¹ K ⁻¹					
Mohs hardness	8,2					
Refractive index	1,82@1064 nm					

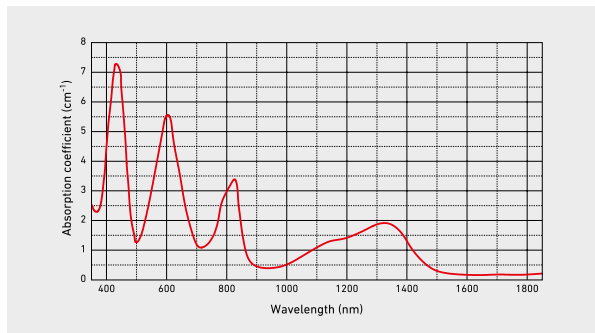
Herewith:

- σ_{gsa}¹ – ground-state absorption cross-section
- σ_{esa}² – excited-state absorption cross-section
- τ_{sa}³ – recovery time
- σ_{em}⁴ – emission cross-section

Standard products

FACE DIMENSIONS	INITIAL TRANSMISSION	COATINGS	SKU	PRICE	
ø3 mm	20%@1064 nm	AR/AR@1064 nm	7279	195 €	
	30%@1064 nm	AR/AR@1064 nm	7280	195 €	
	40%@1064 nm	AR/AR@1064 nm	7281	195 €	
	50%@1064 nm	AR/AR@1064 nm	7282	195 €	
	60%@1064 nm	AR/AR@1064 nm	7283	195 €	
	70%@1064 nm	AR/AR@1064 nm	7284	195 €	
	80%@1064 nm	AR/AR@1064 nm	7285	195 €	
	85%@1064 nm	AR/AR@1064 nm	7286	195 €	
	90%@1064 nm	AR/AR@1064 nm	7287	195 €	
	95%@1064 nm	AR/AR@1064 nm	7288	195 €	
	98%@1064 nm	AR/AR@1064 nm	7289	195 €	
	ø6 mm	20%@1064 nm	AR/AR@1064 nm	7301	225 €
		30%@1064 nm	AR/AR@1064 nm	7302	225 €
		40%@1064 nm	AR/AR@1064 nm	7303	225 €
50%@1064 nm		AR/AR@1064 nm	7304	225 €	
60%@1064 nm		AR/AR@1064 nm	7305	225 €	
70%@1064 nm		AR/AR@1064 nm	7306	225 €	
80%@1064 nm		AR/AR@1064 nm	7307	225 €	
85%@1064 nm		AR/AR@1064 nm	7308	225 €	
90%@1064 nm		AR/AR@1064 nm	7309	225 €	
95%@1064 nm		AR/AR@1064 nm	7310	225 €	
98%@1064 nm		AR/AR@1064 nm	7311	225 €	
3 x 3 mm		20%@1064 nm	AR/AR@1064 nm	7290	195 €
		30%@1064 nm	AR/AR@1064 nm	7291	195 €
		40%@1064 nm	AR/AR@1064 nm	7292	195 €
	50%@1064 nm	AR/AR@1064 nm	7293	195 €	
	60%@1064 nm	AR/AR@1064 nm	7294	195 €	
	70%@1064 nm	AR/AR@1064 nm	7295	195 €	
	80%@1064 nm	AR/AR@1064 nm	7296	195 €	
	85%@1064 nm	AR/AR@1064 nm	7297	195 €	
	90%@1064 nm	AR/AR@1064 nm	7298	195 €	
	95%@1064 nm	AR/AR@1064 nm	7299	195 €	
	98%@1064 nm	AR/AR@1064 nm	7300	195 €	

V:YAG crystals



V:YAG is a relatively new saturable absorber. Passive Q-switch operation is available in the spectral range from 1064 nm to 1440 nm, primarily because of an extremely high ground state. These crystals can be used with active laser media such as Nd:YAG, Nd:YAP,

Nd:KGW, Nd:YVO₄ and provide good lasing characteristics in passive Q-switched lasers. V:YAG features excellent optical, mechanical, and thermal properties and can be grown by Czochralski method.

Main features

- High ground state absorption
- Insignificant excited state absorption
- High contrast of the Q-switch
- Good optical, mechanical, and thermal properties
- UV-resistant and features a high damage threshold
- Custom crystals available upon request

Application examples

- Passively Q-switched lasers for laser rangefinders, LIDAR, and LIBS systems

Standard specifications

V:YAG CRYSTALS	
Initial transmission T ₀	30-98%@1340 nm
Initial transmission T ₀ tolerance	±1% (for values larger than 80%)
Clear aperture	>90%
Face dimensions tolerance	+0,0/-0,1 mm
Parallelism error	<20 arcsec
Perpendicularity error	<10 arcmin
Protective chamfers	<0,1 mm at 45°
Surface quality	10-5 S-D
Surface flatness	<λ/8@632,8 nm
Wavefront distortion	<λ/4@632,8
Coatings	AR(R<0,2%)@1310-1360 nm on both sides
Laser induced damage threshold	>10 J/cm²@1340 nm, 10 ns
Mount	Unmounted

Properties

SPECTROSCOPIC AND THERMO-MECHANICAL PROPERTIES						
Material	$\sigma_{gsa}^{(1)}$ @1,34 μ m	$\sigma_{esa}^{(2)}$ @1,34 μ m	$\tau_{sa}^{(3)}$	Laser crystal	λ_{laser}	$\sigma_{gsa}/\sigma_{em}^{(4)}$
V ²⁺ :Y ₃ Al ₅ O ₁₂	72×10^{-19} cm ²	$7,4 \times 10^{-19}$ cm ²	5-37 ns	Pr:YAP	0,747 μ m	10
				Ti:Al ₂ O ₃	0,78 μ m	25
				Cr:LiCAF	0,78 μ m	80
				Nd:GGG	0,93 μ m	-
				Nd:YLF	1,05 μ m	15
				Nd:YAG	1,06 μ m	8
				Nd:YVO ₄	1,06 μ m	1,5
				Yb:KYW	1,035 μ m	70
				Nd:YAP	1,34 μ m	24
				Nd:GdVO ₄	1,34 μ m	30
				Er:glass	1,54 μ m	45
				Crystal structure	Cubic	
Density	4,56 g/cm ³					
Thermal expansion coefficient	$6,14 \times 10^{-6}$ K ⁻¹					
Thermal conductivity	11,2 Wm ⁻¹ K ⁻¹					
Mohs hardness	8,2					
Refractive index	1,82@1064 nm					

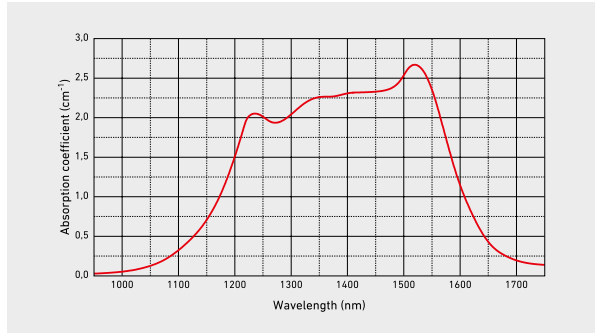
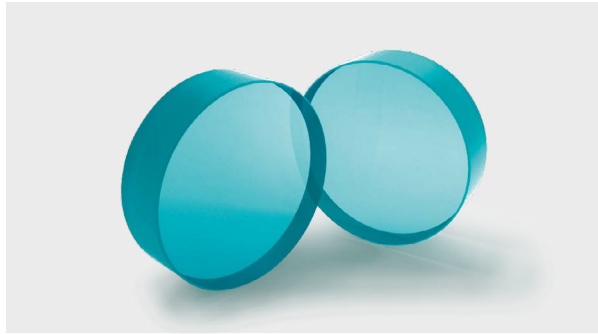
Herewith:

- $\sigma_{gsa}^{(1)}$ – ground-state absorption cross-section
- $\sigma_{esa}^{(2)}$ – excited-state absorption cross-section
- $\tau_{sa}^{(3)}$ – recovery time
- $\sigma_{em}^{(4)}$ – emission cross-section

Standard products

FACE DIMENSIONS	INITIAL TRANSMISSION	COATINGS	SKU	PRICE
ø5 mm	30%@1340 nm	AR/AR@1310-1360 nm	7321	540 €
	40%@1340 nm	AR/AR@1310-1360 nm	7322	540 €
	50%@1340 nm	AR/AR@1310-1360 nm	7323	540 €
	60%@1340 nm	AR/AR@1310-1360 nm	7324	540 €
	70%@1340 nm	AR/AR@1310-1360 nm	7325	540 €
	80%@1340 nm	AR/AR@1310-1360 nm	7326	540 €
	85%@1340 nm	AR/AR@1310-1360 nm	7327	540 €
	90%@1340 nm	AR/AR@1310-1360 nm	7328	540 €
	95%@1340 nm	AR/AR@1310-1360 nm	7329	540 €
3 x 3 mm	30%@1340 nm	AR/AR@1310-1360 nm	7312	540 €
	40%@1340 nm	AR/AR@1310-1360 nm	7313	540 €
	50%@1340 nm	AR/AR@1310-1360 nm	7314	540 €
	60%@1340 nm	AR/AR@1310-1360 nm	7315	540 €
	70%@1340 nm	AR/AR@1310-1360 nm	7316	540 €
	80%@1340 nm	AR/AR@1310-1360 nm	7317	540 €
	85%@1340 nm	AR/AR@1310-1360 nm	7318	540 €
	90%@1340 nm	AR/AR@1310-1360 nm	7319	540 €
	95%@1340 nm	AR/AR@1310-1360 nm	7320	540 €

Co:Spinel crystals



Co:Spinel is a recently developed material, which has been proven to be a very effective passive Q-switch in lasers emitting in the range of 1,2 μm - 1,6 μm . Co:Spinel has a high absorption cross-section, which permits Q-switch operation of Er:glass laser (both flash-lamp

and diode-laser pumped) without an intracavity focusing. Negligible excited-state absorption results in a high contrast Q-switch operation, the ratio of initial (small signal) to saturated absorption is higher than 10.

Main features

- Low optical losses in the wavelength range of 1,3 μm - 1,6 μm
- High laser induced damage threshold
- Custom crystals available upon request

Application examples

- Passive Q-switch for Er:Glass lasers @1,54 μm

Standard specifications

CO:SPINEL CRYSTALS	
Available initial T_0 transmission	50-99 % @1535 nm
Initial transmission T_0 tolerance	$\pm 1\%$ (for values larger than 80%)
Clear aperture	>90%
Face dimensions tolerance	+0,0/-0,1 mm
Parallelism error	<20 arcsec
Perpendicularity error	<10 arcmin
Protective chamfers	<0,1 mm at 45°
Surface quality	20-10 S-D
Surface flatness	< $\lambda/8$ @632,8 nm
Wavefront distortion	< $\lambda/4$ @632,8 nm
Coatings	AR(R<0,15%) @1535 nm
Laser induced damage threshold	>8 J/cm² @1535 nm, 10 ns
Mount	Unmounted

Properties

SPECTROSCOPIC AND THERMO-MECHANICAL PROPERTIES						
Material	$\sigma_{gsa}^{(1)}$ @1,54 μm	$\sigma_{esa}^{(2)}$ @1,54 μm	$\tau_{sa}^{(3)}$	Laser crystal	λ_{laser}	$\sigma_{gsa}/\sigma_{em}^{(4)}$
Co ²⁺ :MgAl ₂ O ₄	$3,5 \times 10^{-19} \text{ cm}^2$	$0,1 \times 10^{-19} \text{ cm}^2$	220-350 ns	Nd:YAP	1,34 μm	1,5
				Nd:KGW	1,35 μm	4
				Nd:YAG	1,44 μm	12
				Er-glass	1,54 μm	40
Crystal structure	Cubic					
Density	3,58 g/cm ³					
Thermal expansion coefficient	$6,14 \times 10^{-6} \text{ K}^{-1}$					
Thermal conductivity	17 Wm ⁻¹ K ⁻¹					
Mohs hardness	8					
Refractive index	1,6-1,75					

Herewith:

$\sigma_{gsa}^{(1)}$ – ground-state absorption cross-section

$\sigma_{esa}^{(2)}$ – excited-state absorption cross-section

$\tau_{sa}^{(3)}$ – recovery time

$\sigma_{em}^{(4)}$ – emission cross-section

Standard products

FACE DIMENSIONS	INITIAL TRANSMISSION	COATINGS	SKU	PRICE
3 x 3 mm	80% @1535 nm	AR/AR @1535 nm	7331	340 €
	85% @1535 nm	AR/AR @1535 nm	7332	340 €
	90% @1535 nm	AR/AR @1535 nm	7333	340 €
	92% @1535 nm	AR/AR @1535 nm	7334	340 €
	95% @1535 nm	AR/AR @1535 nm	7335	340 €
	97% @1535 nm	AR/AR @1535 nm	7336	340 €
5 x 5 mm	80% @1535 nm	AR/AR @1535 nm	7338	390 €
	85% @1535 nm	AR/AR @1535 nm	7339	390 €
	90% @1535 nm	AR/AR @1535 nm	7340	390 €
	92% @1535 nm	AR/AR @1535 nm	7341	390 €
	95% @1535 nm	AR/AR @1535 nm	7342	390 €
	97% @1535 nm	AR/AR @1535 nm	7343	390 €